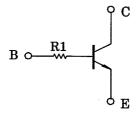
TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT Process)

RN1112F,RN1113F

Switching, Inverter Circuit, Interface Circuit And Driver Circuit Applications

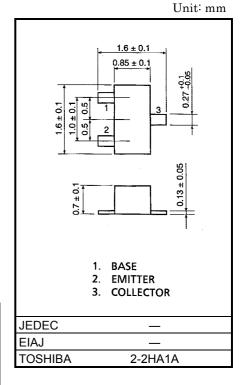
- With built-in bias resistors
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process
- Complementary to RN2112F, RN2113F

Equivalent Circuit



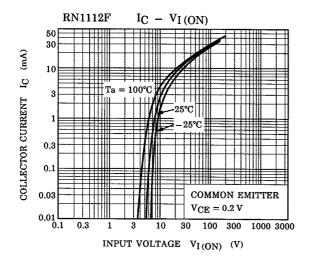
Maximum Ratings (Ta = 25°C)

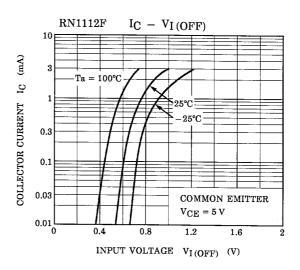
Characterisstic	Symbol	Rating	Unit
Collector-base voltage	V_{CBO}	50	V
Collector-emitter voltage	V_{CEO}	50	V
Emitter-base voltage	V _{EBO}	5	V
Collector current	Ic	100	mA
Collector power dissipation	P _c	100	mW
Junction temperature	Tj	150	°C
Storage temperature range	T _{stg}	-55~150	°C

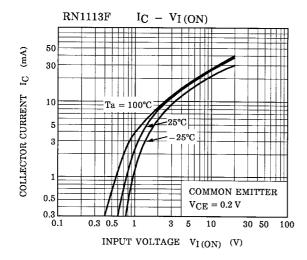


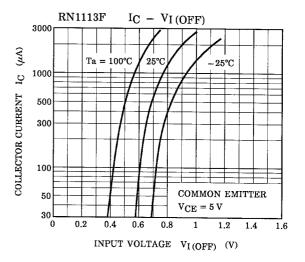
Electrical Characteristics (Ta = 25°C)

Characteristic		Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current		I _{CBO}	_	V _{CB} = 50V, I _E = 0	_	_	100	nA
Emitter cut-off current		I _{EBO}	_	V _{EB} = 5V, I _C = 0	_	_	100	nA
DC current gain		h _{FE}	_	V _{CE} = 5V, I _C = 1mA	120	_	700	_
Collector-emitter saturation voltage		V _{CE} (sat)	_	I _C = 5mA, I _B = 0.25mA	_	0.1	0.3	V
Translation frequency		f _T	_	V _{CE} = 10V, I _C = 5mA	_	250	_	MHz
Collector output capacitance		C _{ob}	_	V _{CB} = 10V, I _E = 0, f = 1MHz	_	3	6	pF
Input resistor	RN1112F	R1	_	-	15.4	22	28.6	kΩ
	RN1113F				32.9	47	61.1	

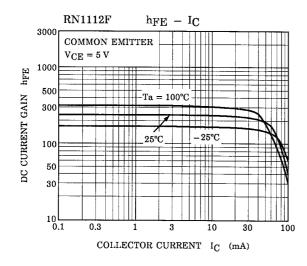


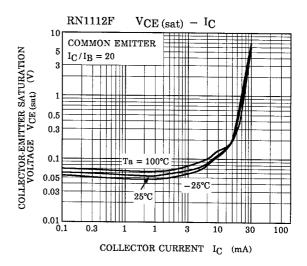


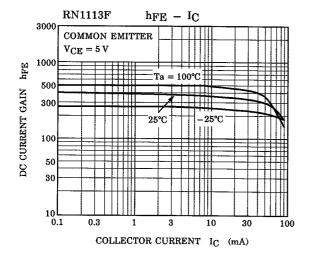


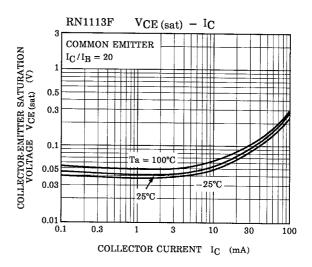


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Type Name	Marking	
RN1112F	Type Name X N	
RN1113F	Type Name X P	

4

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